

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,399,693 B2  
APPLICATION NO. : 10/566170  
DATED : July 15, 2008  
INVENTOR(S) : Yoshinobu Sekiguchi

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

**COLUMN 12:**

Line 57, "Al<sub>0.13</sub>Ga<sub>0.87</sub> layer 30." should read -- Al<sub>0.13</sub>Ga<sub>0.87</sub> As layer 30: --.

**COLUMN 16:**

Line 25, "microc." should read -- micro- --; and

Line 26, "rystalline" should read -- crystalline --.

Signed and Sealed this

Third Day of March, 2009



JOHN DOLL  
*Acting Director of the United States Patent and Trademark Office*